

Switchmode Full Plastic Dual Schottky Barrier Power Rectifiers

Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- *Glass Passivated chip junctions
- *Low Reverse Leakage Current
- *Fast Switching for High Efficiency
- *150°C Operating Junction Temperature
- *Low Stored Charge Majority Carrier Conduction
- *Low Forward Voltage , High Current Capability
- *Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O



* In compliance with EU RoHs 2002/95/EC directives

MAXIMUM RATINGS

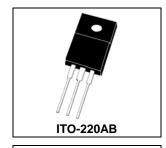
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Characteristic	Symbol	FRF1620K	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	200	V
RMS Reverse Voltage	V _{R(RMS)}	140	V
Average Rectifier Forward Current (per diode) Per Total Device	I _{F(AV)}	8 16	А
Peak Repetitive Forward Current (Rate V _R , Square Wave, 20kHz)	I _{FM}	16	А
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware, single phase, 60Hz)	I _{FSM}	100	А
Operating and Storage Junction Temperature Range	T_J,T_stg	-65 to +150	$^{\circ}\!\mathbb{C}$

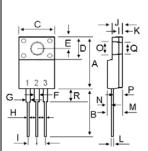
ELECTRIAL CHARACTERISTICS

Characteristic	Symbol	FRF1620K	Unit	
Maximum Instantaneous Forward Voltage ($I_F = 8 \text{ Amp } T_C = 25^{\circ}C$ per diode)	V _F	1.10	V	
Maximum Instantaneous Reverse Current (Rated DC Voltage, T _C = 25°C) (Rated DC Voltage, T _C = 125°C)	I _R	1 100	uA	
Reverse Recovery Time ($I_F = 0.5 \text{ A}$, $I_R = 1.0$, $I_{rr} = 0.25 \text{ A}$)	T _{rr}	30	ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	СР	55	₽F	

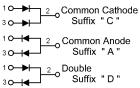
FAST RECOVERY RECTIFIERS

16 AMPERES 200 VOLTS

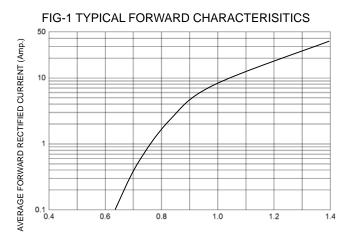




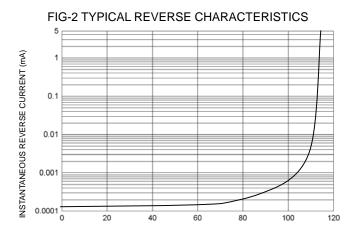
	MILLIMETERS		
DIM	MIN	MAX	
Α	14.90	15.15	
В	13.35	13.55	
С	10.00	10.10	
D	6.55	6.65	
Е	2.65	2.75	
F	1.55	1.65	
G	1.15	1.25	
Н	0.55	0.65	
- 1	2.50	2.60	
J	3.00	3.20	
K	1.10	1.20	
L	0.55	0.65	
М	4.40	4.60	
N	1.15	1.25	
0	3.35	3.45	
Р	2.65	2.75	
Q	3.15	3.25	
R	3.60	3.80	



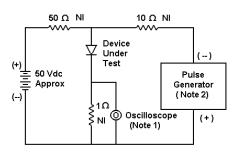
FRF1620K



FORWARD VOLTAGE (Volts)



PERCENT OF PEAK REVERSE VOLTAGE (%)



- 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω

FIG-3 FORWARD CURRENT DERATING CURVE

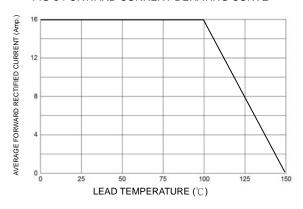


FIG-4TYPICAL JUNCTION CAPACITANCE

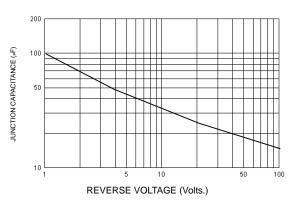
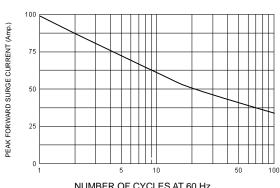
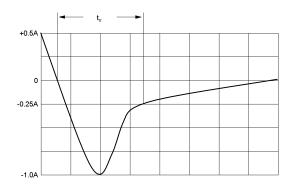


FIG-5PEAK FORWARD SURGE CURRENT



NUMBER OF CYCLES AT 60 Hz



Set time base for 20/50 ns/cm

FIG-6 Reverse Recovery Time Characteristic and Test Circuit Diagram



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